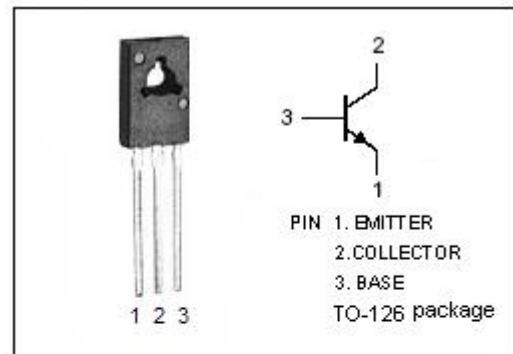


isc Silicon NPN Power Transistor
2SC3902
DESCRIPTION

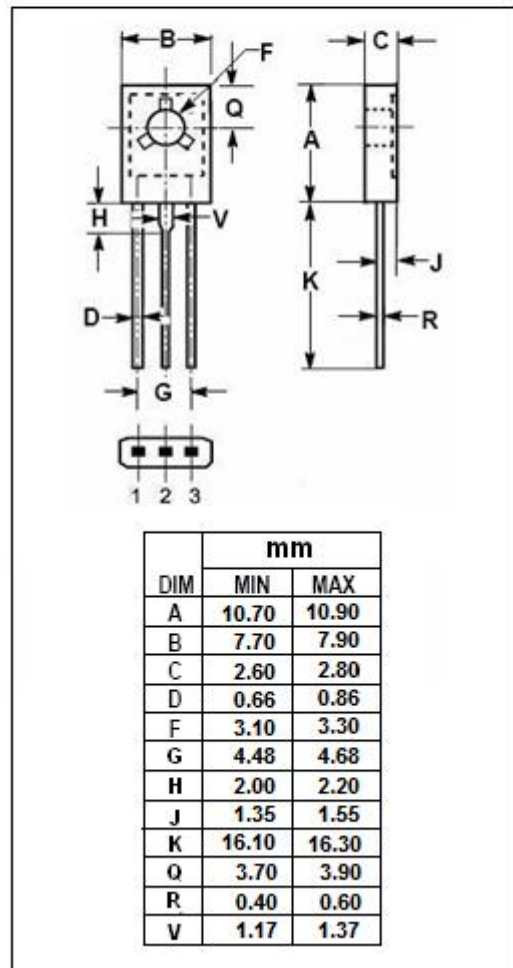
- High Collector-Emitter Breakdown Voltage-
: $V_{(BR)CEO} = 160V(\text{Min})$
- Large Current Capacity
- Complement to Type 2SA1507
- 100% avalanche tested
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

APPLICATIONS

- Color TV audio output, converters, inverters.


ABSOLUTE MAXIMUM RATINGS($T_a=25^\circ\text{C}$)

| SYMBOL | PARAMETER | VALUE | UNIT |
|-----------|---|---------|------------------|
| V_{CBO} | Collector-Base Voltage | 180 | V |
| V_{CEO} | Collector-Emitter Voltage | 160 | V |
| V_{EBO} | Emitter-Base Voltage | 6 | V |
| I_C | Collector Current-Continuous | 1.5 | A |
| I_{CM} | Collector Current-Peak | 2.5 | A |
| P_C | Collector Power Dissipation @ $T_c=25^\circ\text{C}$ | 10 | W |
| | Collector Power Dissipation @ $T_a=25^\circ\text{C}$ | 1.5 | |
| T_J | Junction Temperature | 150 | $^\circ\text{C}$ |
| T_{stg} | Storage Temperature Range | -55~150 | $^\circ\text{C}$ |



isc Silicon NPN Power Transistor
2SC3902
ELECTRICAL CHARACTERISTICS
 $T_C=25^{\circ}\text{C}$ unless otherwise specified

| SYMBOL | PARAMETER | CONDITIONS | MIN | TYP. | MAX | UNIT |
|---------------|--------------------------------------|--|-----|------|------|---------------|
| $V_{(BR)CBO}$ | Collector-Base Breakdown Voltage | $I_C=10\mu\text{A}; I_E=0$ | 180 | | | V |
| $V_{(BR)CEO}$ | Collector-Emitter Breakdown Voltage | $I_C=1\text{mA}; R_{BE}=\infty$ | 160 | | | V |
| $V_{(BR)EBO}$ | Emitter-Base Breakdown Voltage | $I_E=10\mu\text{A}; I_C=0$ | 6 | | | V |
| $V_{CE(sat)}$ | Collector-Emitter Saturation Voltage | $I_C=500\text{mA}; I_B=50\text{mA}$ | | | 0.45 | V |
| $V_{BE(sat)}$ | Base-Emitter Saturation Voltage | $I_C=500\text{mA}; I_B=50\text{mA}$ | | | 1.2 | V |
| I_{CBO} | Collector Cutoff Current | $V_{CB}=120\text{V}; I_E=0$ | | | 0.1 | μA |
| I_{EBO} | Emitter Cutoff Current | $V_{EB}=4\text{V}; I_C=0$ | | | 0.1 | μA |
| h_{FE} | DC Current Gain | $I_C=10\text{mA}; V_{CE}=5\text{V}$ | 100 | | 400 | |
| f_T | Current-Gain—Bandwidth Product | $I_C=50\text{mA}; V_{CE}=10\text{V}$ | | 120 | | MHz |
| C_{OB} | Output Capacitance | $I_E=0; V_{CB}=10\text{V}; f_{test}=1\text{MHz}$ | | 14 | | pF |

Switching Times

| | | | | | | |
|-----------|--------------|---|--|------|--|---------------|
| t_{on} | Turn-on Time | $I_C=0.7\text{A}, I_{B1}=-I_{B2}=70\text{mA}$ $R_L=14.3\Omega; V_{CC}=100\text{V}$ | | 0.04 | | μs |
| t_{stg} | Storage Time | | | 1.2 | | μs |
| t_f | Fall Time | | | 0.08 | | μs |

◆ h_{FE} Classifications

| R | S | T |
|---------|---------|---------|
| 100-200 | 140-280 | 200-400 |

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